## CMKT5089M10

SURFACE MOUNT DUAL NPN SILICON MATCHED  $h_{\mbox{\scriptsize FE}}$  TRANSISTORS





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# **DESCRIPTION:**

The CENTRAL SEMICONDUCTOR CMKT5089M10 consists of two (2) individually isolated 5089 NPN silicon transistors with matched hFE. This ULTRAmini™ device is manufactured by the epitaxial planar process and epoxy molded in an SOT-363 surface mount package. The CMKT5089M10 has been designed for applications requiring high gain and low noise.

MARKING CODE: C9M0

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MAXIMUM RA	TINGS: (T <sub>A</sub> =25°C)	SYMBOL		UNITS
Collector-Base	Voltage	$V_{CBO}$	30	V
Collector-Emitte	er Voltage	$V_{CEO}$	25	V
Emitter-Base V	oltage	$V_{EBO}$	4.5	V
Continuous Co	llector Current	$I_{\mathbb{C}}$	50	mA
Power Dissipat	ion	$P_{D}$	350	mW
Operating and	Storage Junction Temperature	T <sub>J</sub> , T <sub>stg</sub>	-65 to +150	°C
Thermal Resist	ance	$\Theta_{\sf JA}$	357	°C/W
ELECTRICAL	CHARACTERISTICS PER TRAN	ISISTOR: (T <sub>A</sub> =25°C	unless otherwise noted	d)
SYMBOL	TEST CONDITIONS	MIN	MAX	UNITS
I <sub>CBO</sub>	V <sub>CB</sub> =15V		50	nA
I <sub>EBO</sub>	V <sub>EB</sub> =4.5V		100	nA
BV <sub>CBO</sub>	I <sub>C</sub> =100μA	30		V
BV <sub>CEO</sub>	I <sub>C</sub> =1.0mA	25		V

I <sub>CBO</sub>	V <sub>CB</sub> =15V		50	nA
I <sub>EBO</sub>	V <sub>EB</sub> =4.5V		100	nA
BV <sub>CBO</sub>	I <sub>C</sub> =100μA	30		V
BV <sub>CEO</sub>	I <sub>C</sub> =1.0mA	25		V
BVEBO	I <sub>E</sub> =100μA	4.5		V
V <sub>CE</sub> (SAT)	I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA		0.5	V
V <sub>BE(SAT)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =1.0mA		0.8	V
hFE	$V_{CE}$ =5.0V, $I_{C}$ =0.1mA	400	1200	
hFE	$V_{CE}$ =5.0V, $I_{C}$ =1.0mA	450		
h <sub>FE</sub>	$V_{CE}$ =5.0V, $I_{C}$ =10mA	400		
f <sub>T</sub>	$V_{CE}$ =5.0V, $I_{C}$ =500 $\mu$ A, f=20MHz	50		MHz
C <sub>ob</sub>	$V_{CB}$ =5.0V, $I_E$ =0, f=1.0MHz		4.0	pF
C <sub>ib</sub>	$V_{BE}$ =0.5V, $I_{C}$ =0, f=1.0MHz		10	pF
h <sub>fe</sub>	$V_{CE}$ =5.0V, $I_{C}$ =1.0mA, f=1.0kHz	450	1800	
NF	$V_{CE}$ =5.0V, $I_{C}$ =100 $\mu$ A, $R_{S}$ =1.0 $k\Omega$ ,			
	f=10Hz to 15.7kHz		2.0	dB

MATCHING CI SYMBOL	HARACTERISTICS: TEST CONDITIONS	MIN	MAX	UNITS
h <sub>FE1</sub> /h <sub>FE2</sub> *	$V_{CE}$ =5.0V, $I_{C}$ =1.0mA	0.9	1.0	
V <sub>BE1</sub> -V <sub>BE2</sub>	V <sub>C</sub> F=5.0V, I <sub>C</sub> =100μA		5.0	mV

<sup>\*</sup> The lowest hFE reading is taken as hFE1.

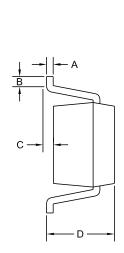
R4 (13-January 2010)

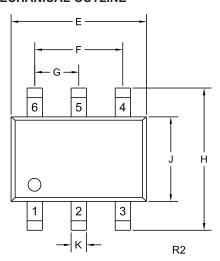
## CMKT5089M10

# **SURFACE MOUNT DUAL NPN SILICON** ${\tt MATCHED}\; {\tt h_{FE}}\; {\tt TRANSISTORS}$

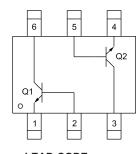


## **SOT-363 CASE - MECHANICAL OUTLINE**





## **PIN CONFIGURATION**



# LEAD CODE:

- 1) Emitter Q1 2) Base Q1
- 3) Collector Q2
- 4) Emitter Q2
- 5) Base Q2
- 6) Collector Q1

MARKING CODE: C9M0

DIMENSIONS				
	INCHES		MILLIMETERS	
SYMBOL	MIN	MAX	MIN	MAX
Α	0.004	0.010	0.10	0.25
В	0.005	-	0.12	-
С	0.000	0.004	0.00	0.10
D	0.031	0.043	0.80	1.10
Е	0.071	0.087	1.80	2.20
F	0.051		1.30	
G	0.026		0.65	
Н	0.075	0.091	1.90	2.30
J	0.043	0.055	1.10	1.40
K	0.006	0.012	0.15	0.30

SOT-363 (REV: R2)

R4 (13-January 2010)

## **OUTSTANDING SUPPORT AND SUPERIOR SERVICES**



#### PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

#### **DESIGNER SUPPORT/SERVICES**

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2<sup>nd</sup> day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- · Custom product and package development

#### REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

#### **CONTACT US**

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